Citation Report
List of articles citing

Near-unity photoluminescence quantum yield in MoS2

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#	Paper	IF	Citations
890	Recombination Kinetics and Effects of Superacid Treatment in Sulfur- and Selenium-Based Transition Metal Dichalcogenides.		1
889	Spatially Precise Transfer of Patterned Monolayer WS2 and MoS2 with Features Larger than 104 m2 Directly from Multilayer Sources.		
888	Surfactant-Mediated Growth and Patterning of Atomically Thin Transition Metal Dichalcogenides.		
887	Physically Unclonable Cryptographic Primitives by Chemical Vapor Deposition of Layered MoS2.		
886	Graphene against Other Two-Dimensional Materials: A Comparative Study on the Basis of Electronic Applications. **2016**,		3
885	Optoelectronic Devices Based on Atomically Thin Transition Metal Dichalcogenides. **2016**, 6, 78		74
884	Two-Dimensional Semiconductor Optoelectronics Based on van der Waals Heterostructures. **2016**, 6,		79
883	Layer-Controlled Chemical Vapor Deposition Growth of MoS2 Vertical Heterostructures via van der Waals Epitaxy. **2016**, 10, 7039-46		97
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